

1EDI60H12AHXUMA1

Data Sheet

Dual Galvanic Isolated MOSFET Power Driver, -9.4 A, 10 A, $3.1 \rightarrow 17 \text{ V 8-Pin}$, DSO

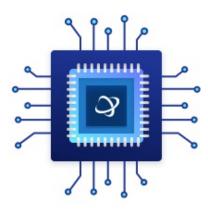
Manufacturers Infineon Technologies Corporation

Package/Case

Electromechanical Product Type

RoHS

Lifecycle



Images are for reference only

Please submit RFQ for 1EDI60H12AHXUMA1 or <u>Emailto:sales@ovaga.com</u> We will contact you in 12 hours.

RFO

General Description

EiceDRIVER™ 1200 V high side gate driver IC with typical typical 10.0 A source and 9.4 A sink currents in DSO-8 package for IGBT.

Features Application

1200V coreless Transformer isolated Driver ICs Motor control and drives

6 A rail-to-rail outputs Solutions for solar energy systems

300 mil wide-body package for 8 mm creepage distance Power supplies (SMPS)

Separate source/sink outputs Automotive

Related Products

1ED020I12F2XUMA1

Infineon Technologies Corporation

PG-DSO-16

1ED020I12BTXUMA1

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